NSN 5962-01-290-5575

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-290-5575

Overall Length:
1.490 inches
Overall Height:
0.432 inches
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
170.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Ultraviolet erasable and monolithic and programmed and w/disable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
15 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
140.00 microamperes stand-by
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-2.0 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds access
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit

NSN 5962-01-290-5575

Memory Microcircuit - Page 2 of 2

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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